N-Channel Silicon MOSFET



2SK1446LS

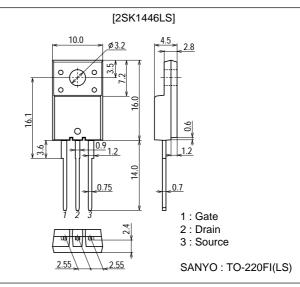
Ultrahigh-Speed Switching Applications

Features

- Low ON-resistance.
- Ultrahigh-speed switching.
- · Micaless package facilitating mounting.

Package Dimensions

unit : mm 2078C



Specifications

Absolute Maximum Ratings at Ta=25°C

Parameter	Symbol	Conditions	Ratings	Unit
Drain-to-Source Voltage	VDSS		450	V
Gate-to-Source Voltage	VGSS		±30	V
Drain Current (DC)	۱D		7	А
Drain Current (Pulse)	IDP	PW≤10µs, duty cycle≤1%	28	А
Allowable Power Dissipation	De		2.0	W
	PD	Tc=25°C	35	W
Channel Temperature	Tch		150	°C
Storage Temperature	Tstg		-55 to +150	°C

Electrical Characteristics at Ta=25°C

Parameter	Symbol	Conditions	Ratings			Unit
			min	typ	max	Unit
Drain-to-Source Breakdown Voltage	V(BR)DSS	ID=1mA, VGS=0	450			V
Zero-Gate Voltage Drain Current	IDSS	VDS=450V, VGS=0			1.0	mA
Gate-to-Source Leakage Current	IGSS	V _{GS} =±30V, V _{DS} =0			±100	nA
Gate-to-Source Leakage Current	IGSS					

(Note) Be careful in handling the 2SK1446LS because it has no protection diode between gate and source.

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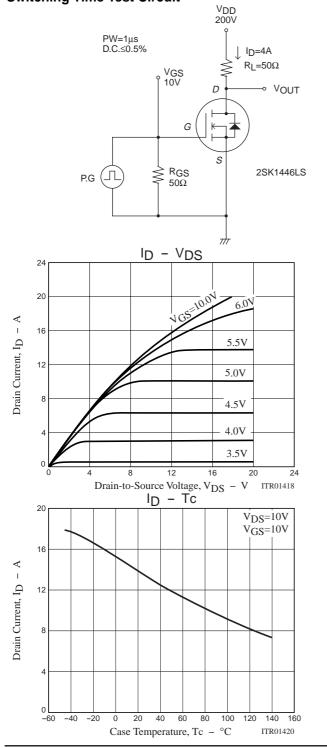
Marking: K1446

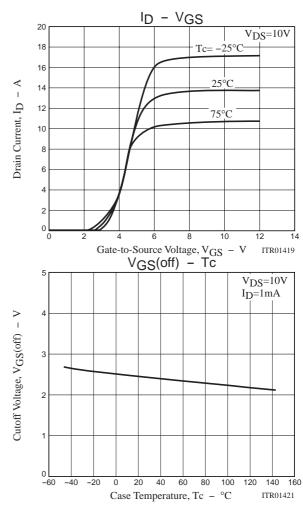
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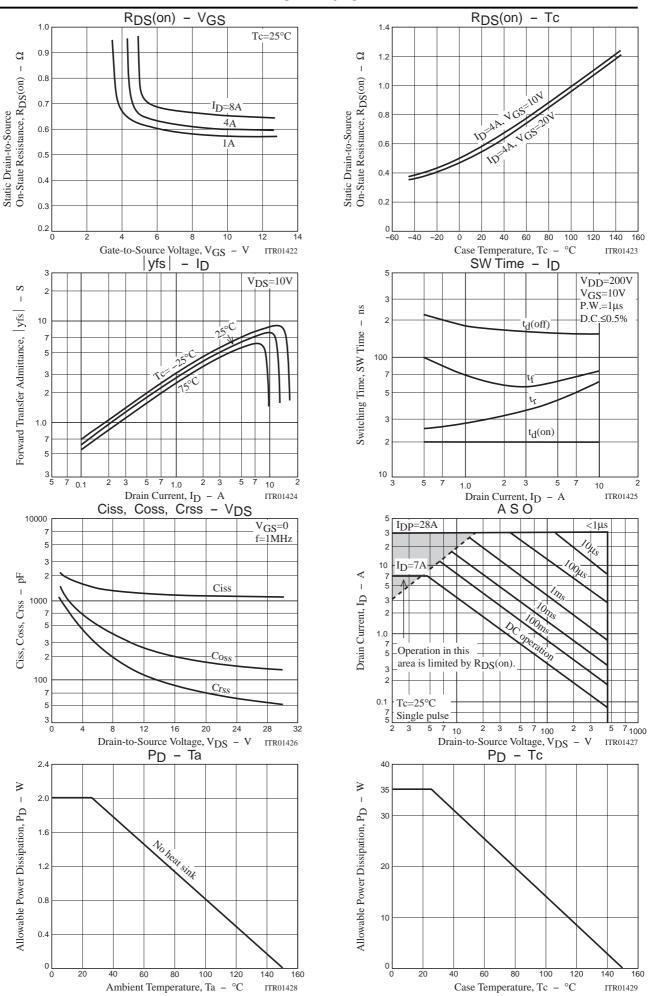
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Parameter	Symbol	Conditions	Ratings			Unit
			min	typ	max	Unit
Cutoff Voltage	VGS(off)	V _{DS} =10V, I _D =1mA	2.0		3.0	V
Forward Transfer Admittance	yfs	V _{DS} =10V, I _D =4A	3.0	6.0		S
Static Drain-to-Source On-State Resistance	RDS(on)	ID=4A, VGS=10V		0.6	0.8	Ω
Input Capacitance	Ciss	V _{DS} =20V, f=1MHz		1200		pF
Output Capacitance	Coss	V _{DS} =20V, f=1MHz		180		pF
Reverse Transfer Capacitance	Crss	VDS=20V, f=1MHz		70		pF
Turn-ON Delay Time	t _d (on)	ID=4A, VGS=10V, VDD=200V, RGS=50 Ω		20		ns
Rise Time	tr	ID=4A, VGS=10V, VDD=200V, RGS=50Ω		40		ns
Turn-OFF Delay Time	t _d (off)	ID=4A, VGS=10V, VDD=200V, RGS=50Ω		160		ns
Fall Time	tf	ID=4A, VGS=10V, VDD=200V, RGS=50Ω		60		ns
Diode Forward Voltage	V _{SD}	IS=7A, VGS=0			1.8	V

Switching Time Test Circuit







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